

10Gbps GaAs PIN Photodiode

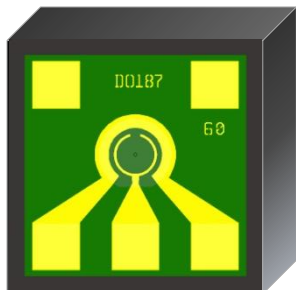
P/N: Do187_60um_PIN4



Known Good Die

DATASHEET

Introduction



This high performance product is a front side illuminated GaAs PIN photodiode chip that features low capacitance, high responsivity, low dark current, and with proven excellent reliability in field. This product has a large 60 μ m detection window, and is primarily designed to be integrated with a pre-amplifier in hermetic TO package, as optical receiver to meet the performance of 10Gbps short-range optical data communication applications operating at 850nm with a 50/125 μ m or 62.5/125 μ m multimode fiber.

Key Features

- Mesa structure with 60 μ m optical detection window
- Top-sided 50 Ω coplanar GSG contact pads with SI substrate
- Excellent low capacitance and extreme low dark current
- -40C to 85C operation range
- Highly robust 4" GaAs IC wafer fab with fast cycle-time
- Deliverable in GCS Known Good Die™ with 100% testing and inspection
- RoHS compliant

Applications

- 10Gbps short range data communication at 850nm
- 10GBASE-SR Ethernet
- 8Gbps Fiber Channel

SPECIFICATIONS (T=25C°)

	Conditions	Min.	Typical	Max.	Unit	Notes
Bandwidth	-3V	-	12.5	-	GHz	
Wavelength range		760	850	860	nm	
Capacitance	-3 V	-	0.18	0.20	pF	
Responsivity	@850 nm	0.5	0.6	-	A/W	
Dark current	-3V	-	<0.1	0.3	nA	
Reverse Breakdown	-20V	-	-	1	μ A	

Absolute Maximum Rating

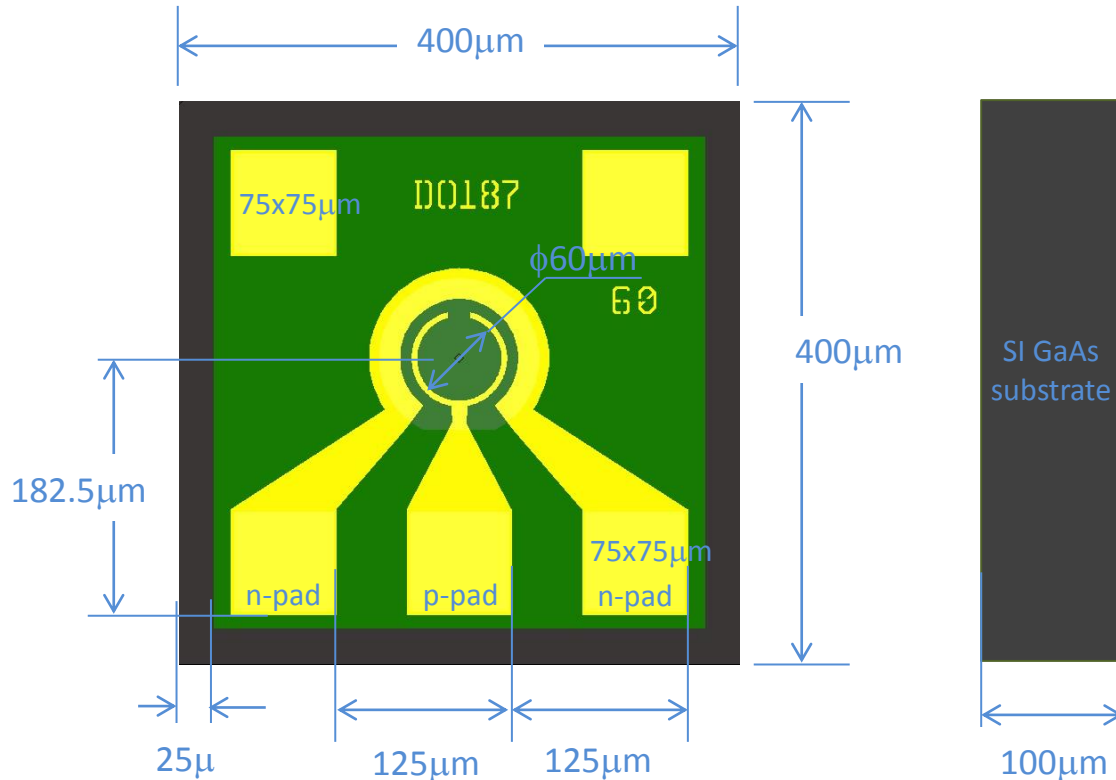
Parameter	Rating
Operating Temperature	-40C to 85C
Storage Temperature	-55C to 125C
Forward Current	10mA



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Dimensions

	Conditions	Min.	Typical	Max.	Unit	Notes
Detection window		-	60	-	μm	
Bonding pad size		-	75x75	-	μm	for both p- and n- pads
Metal height of bond pad		1.4	1.6	-	μm	Au metal
Die height		90	100	110	μm	
Die width		390	400	410	μm	
Die length		390	400	410	μm	



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Attention: GaAs material and electrostatic sensitive device, observe precaution for handling.

Contact Information

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About GCS: GCS has a long history manufacturing and shipping both GaAs and InGaAs based photo diodes since 2000. Our state of art manufacturing facility is located in Torrance, California, and has about 10,000 square feet of fab space with a capability of about 1200 4-inch wafers per month and expandable to 2000 wafers per month. GCS as a world-class semiconductor device manufacturer has been delivering a total of over 30 million photo diodes with various date rates and applications used for optical communications, which have been deployed in field by top tier optical transceiver companies worldwide.



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